

# **MBR735 - MBR760**

#### **Features**

- Low power loss, high efficiency.
- High surge capacity.
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current capacity, low forward voltage drop.
- Guard ring for over voltage protection.





TO-220AC

# **Schottky Rectifiers**

## **Absolute Maximum Ratings\***

T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value				Units
-		735	745	750	760	
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage	35	45	50	60	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	7.5		Α		
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	150				А
T <sub>stg</sub>	Storage Temperature Range	-65 to +175				°C
T <sub>J</sub>	Operating Junction Temperature	-65 to +150				°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Thermal Characteristics**

Symbol	Parameter	Value	Units
P <sub>D</sub>	Power Dissipation	2.0	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	60	°C/W
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	3.0	°C/W

### **Electrical Characteristics**

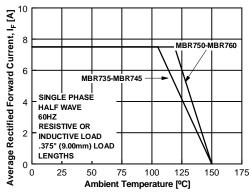
 $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Device				Units
		735	745	750	760	
V <sub>F</sub>	Forward Voltage $I_{F=}$ 7.5 A, $T_{C}$ = 25°C $I_{F=}$ 7.5 A, $T_{C}$ = 125°C $I_{F=}$ 15 A, $T_{C}$ = 25°C $I_{F=}$ 15 A, $T_{C}$ = 125°C	- 0.57 0.84 0.72		0.75 0.65 -		V V V
I <sub>R</sub>	Reverse Current @ rated $V_R$ $T_A = 25^{\circ}C$ $T_A = 125^{\circ}C$	0.1 15		0.5 50		mA mA
I <sub>RRM</sub>	Peak Repetitive Reverse Surge Current 2.0 us Pulse Width, f = 1.0 KHz	1	.0	0.	.5	А

## **Schottky Rectifier**

(continued)

# **Typical Characteristics**



**Figure 1. Forward Current Derating Curve** 

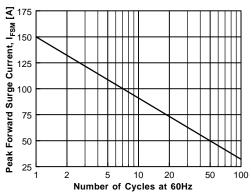


Figure 2. Non-Repetitive Surge Current

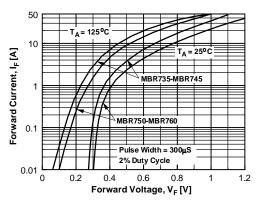


Figure 3. Forward Voltage Characteristics

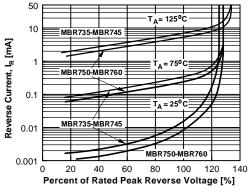


Figure 4. Reverse Current vs Reverse Voltage

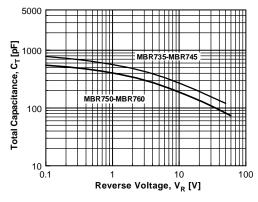


Figure 5. Total Capacitance

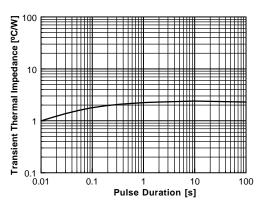


Figure 6. Thermal Impedance Characteristics

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